

2STN2540-A

Low voltage fast-switching PNP power bipolar transistor

Features

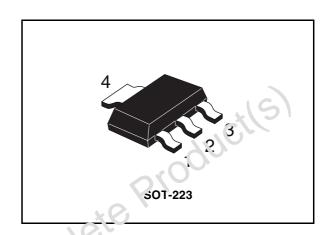
- The device is qualified for automotive application
- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed
- Surface mounting device in medium power SOT-223 package

Applications

- Emergency lighting
- LED
- CCFL drivers (back lighting)
- Voltage regulation
- Relay driver

Description

The device in a PNP transition manufactured using new "PB-HCP" (Fower Bipolar High Current Density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.



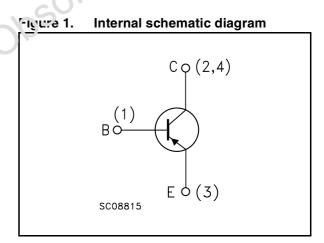


Table 1. Device summary

Order code	Marking	Package	Packaging
2STN2540-	N2540	SOT-223	Tape & reel

Electrical ratings 2STN2540-A

1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-40	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-40	٧
V _{EBO}	Emitter-base voltage ($I_C = 0$)	-6	٧
I _C	Collector current	-5	Α
I _{CM}	Collector peak current (t _P < 5ms)	-10	Α
I _{BM}	Base peak current (t _P < 5ms)	-2	Α
P _{tot}	Total dissipation at T _{amb} = 25°C	0.0	W
T _{stg}	Storage temperature	-65 to 150	°C
T _J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter		Value	Unit
R _{thj-amb} ⁽¹⁾	Thermal resistance junction-amb	max	78	°C/W

^{1.} Device mounted on PCB are a of 10n ²

2 Electrical characteristics

 $(T_{case} = 25 \, ^{\circ}C \text{ unless otherwise specified})$

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E =0)	V _{CB} = -30 V			-0.1	μА
I _{EBO}	Emitter cut-off current (I _C =0)	V _{EB} = -5 V			-0.1	μА
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$\begin{split} & I_{C} = -0.5 \text{ A} & I_{B} = -5 \text{ mA} \\ & I_{C} = -1 \text{ A} & I_{B} = -10 \text{ mA} \\ & I_{C} = -2 \text{ A} & I_{B} = -200 \text{ mA} \\ & I_{C} = -5 \text{ A} & I_{B} = -500 \text{ mA} \end{split}$.(0	-80 -120 -140 -350	-1.20 180 -200 -450	mV mV mV
V _{BE(sat)} (1)	Base-emitter saturation voltage	$I_C = -5$ A $I_B = -500$ mA			-1.3	V
V _{BE(on)} (1)	Base-emitter on voltage	V _{CE} = -2 V I _C 2 A			-1.25	V
h _{FE} ⁽¹⁾	DC current gain	$\begin{aligned} & I_{C} = -2.5 \text{ A} & V_{CE} = -2 \text{ V} \\ & I_{C} = -1 \text{ A} & V_{CE} = -2 \text{ V} \\ & I_{C} = -2 \text{ A} & V_{CE} = -2 \text{ V} \\ & I_{C} = -5 \text{ A} & V_{CE} = -2 \text{ V} \end{aligned}$	250 200 150 50			
C _{CBO}	Collector-๖๘s ว capacita.างว	$I_E = 0$ $V_{CB} = -10 \text{ V}$ $f = 1 \text{MHz}$		80		pF
t _{c1}	Resistive load Turn-on time Storage time Fall time	$I_C = -1 \text{ A}$ $V_{CC} = -10 \text{ V}$ $-I_{B1} = I_{B2} = -0.1 \text{ A}$ $T_p = 30 \mu\text{A}$		75 426 62		ns ns ns

^{1.} Pulsed duration = 300 μs, duty cycle ≤1.5%

Electrical characteristics 2STN2540-A

2.1 Electrical characteristics (curves)

Figure 2. Output characteristics

Figure 3. DC current gain

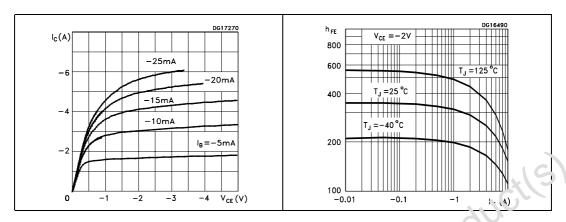


Figure 4. Collector-emitter saturation voltage

Figure 5. Base-emitter saturation voltage

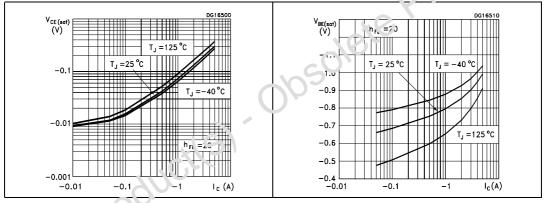


Figure 6. Bas 9-Emitter on voltage

Figure 7. Resistive load switching times

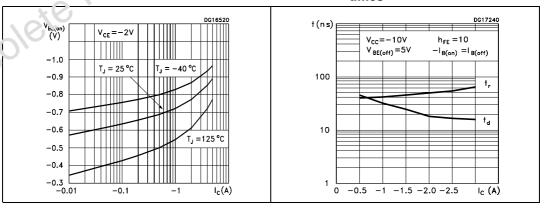
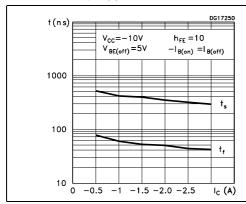
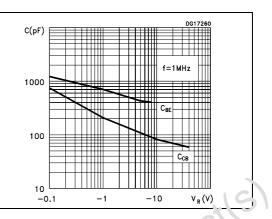


Figure 8. Resistive load switching times

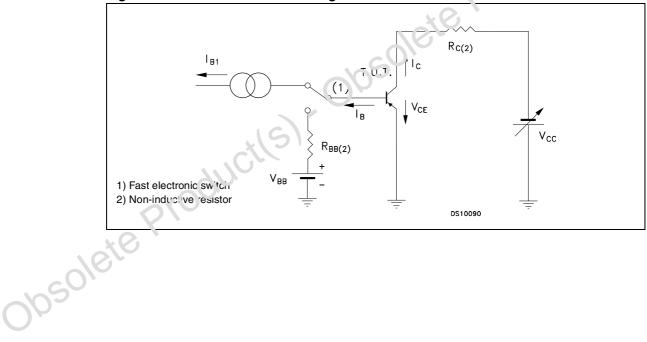
Figure 9. Capacitance





2.2 Test circuit

Figure 10. Resistive load switching test circuit



6/9

577

3 Package mechanical data

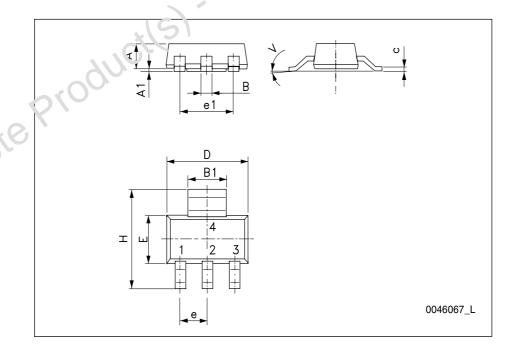
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

Obsolete Producits). Obsolete Producits

Figure 11. Package mechanical data

SOT-223 mechanical data

DIM.	mm.				
	min.	typ	max.		
Α			1.80		
A1	0.02		0.1		
В	0.60	0.70	0.85		
B1	2.90	3.00	3.15		
С	0.24	0.26	Ç 3,7		
D	6.30	6.50	6.70		
е		2.30			
e1		4.60			
E	3.30	3.50	3.70		
Н	6.70	7.00	7.30		
V		70	10 °		



577

Revision history 2STN2540-A

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
23-Oct-2007	1	Initial release
15-Jan-2008	2	Updated max package dimensions in lines "B" and "c" of the package mechanical data, <i>Figure 11</i> .

Obsolete Product(s). Obsolete Product(s)

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its stibs. dicties ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and set rices described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be doesned an cense grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND CONTROL OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZE REPRESENTATIVE OF ST, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZEL OF WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS, WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY CALLY SE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale (f S *products with provisions different from the statements and/or technical features set forth in this document shall immediately void any ...ar anty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any ability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2008 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

